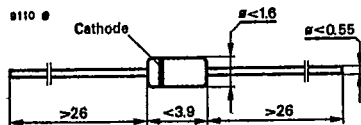




**TELEFUNKEN electronic**  
Creative Technologies

**BAY 93****T-03-09****Silicon Epitaxial Planar Diode****Applications:** Very fast switches**Dimensions in mm****Marking:** By letters

Standard glass case  
54A2 DIN 41880  
JEDEC DO 35  
Weight max. 0.15 g

**Absolute maximum ratings**

Repetitive peak reverse voltage	$V_{RRM}$	25	V
Reverse voltage	$V_R$	20	V
Surge forward current $t_p = 1 \mu s$	$I_{FSM}$	2	A
Repetitive peak forward current	$I_{FRM}$	225	mA
Forward current	$I_F$	200	mA
Average forward current $V_R = 0$	$I_{FAV}$	75	mA
Power dissipation $I = 4 \text{ mm}, T_L = 45^\circ \text{C}$	$P_V$	440	mW
$T_L \leq 25^\circ \text{C}$	$P_V$	500	mW
Junction temperature	$T_j$	200	$^\circ \text{C}$
Storage temperature range	$T_{stg}$	- 55.....+ 200	$^\circ \text{C}$

**Maximum thermal resistance**

Junction ambient $I = 4 \text{ mm}, T_L = \text{constant}$	$R_{thJA}$	350	K/W
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Characteristics		Min.	Typ.	Max.
$T_j = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified				
Forward voltage				
$I_F = 10\text{ mA}$	$V_F$			1 V
Reverse current				
$V_R = 10\text{ V}, T_j = 150\text{ }^{\circ}\text{C}$	$I_R$			100 $\mu\text{A}$
Breakdown voltage				
$I_R = 1\text{ }\mu\text{A}$	$V_{(BR)}^{1)}$	20		V
Diode capacitance				
$V_R = 0, f = 1\text{ MHz}, V_{HF} = 50\text{ mV}$	$C_D$			5 pF
Reverse recovery time				
$I_F = I_R = 10\text{ mA}, I_R = 1\text{ mA}$	$t_{rr}$			15 ns

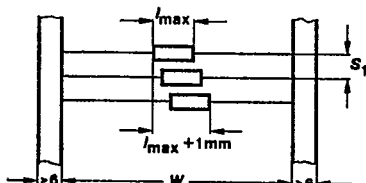
<sup>1)</sup>  $\frac{t_p}{T} = 0.01, t_p = 0.3\text{ ms}$

## 8. Taped devices

## 8.1. Tape specification for diodes and rectifiers with axial leads

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Diodes and rectifiers with axial leads are normally delivered in taped form, according to IEC 286-1 (see Fig. 8.1). The cathode side is designated by a coloured tape. Tape devices are delivered either on reels (normal version), or on request folded in cartons (Ammopack). The GPS-version is normally delivered in Ammopack. Diodes in DO 35 package are also available as radial taped. For details please contact factory.



$$S_1 = 5 \pm 0.5 \text{ for devices with diameter } d < 4.5 \text{ mm}$$

$$= 10 \pm 0.5 \text{ mm for devices with diameter } d > 4.5 \text{ mm}$$

$$W = 53 \pm 2 \text{ mm for normal taped form}$$

$$= 26 \pm 1.5 \text{ for GPS version}$$

Allowable deviation above 10 taped steps  $\pm 2$  mm

Fig. 8.1 Standard taped diodes with axial leads

## 8.2. Tape specifications for Surface Mounted Devices (SMDs)

SMDs are delivered either bulk packed or taped on blister tape according to IEC 286-3. The mounting side is oriented to the bottom side of the tape.

For standard taping suffix "GS 08" is added to the type number.

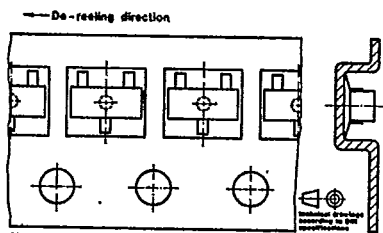


Fig. 8.2 Standard taped SOD 80

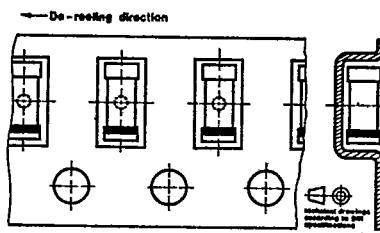


Fig. 8.3 Standard taped SOT 23

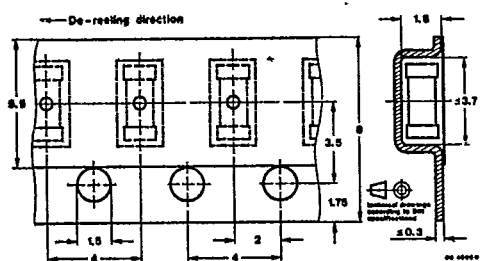


Fig. 8.4 Tape dimensions for SOD 80 in mm

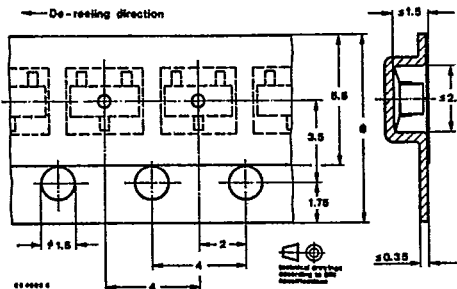


Fig. 8.5 Tape dimensions for SOT 23 and SOT 143 in mm

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Quantities per reel: SOD 80 - 2500 comp. SOT 23 - 3000 comp. SOT 143 - 3000 comp.

Missing devices: Maximum of 0.5 % of the total number of components per reel may be missing exclusively missing components at the beginning and at the end of the reel. Maximum of three consecutive components may be missing, provided this gap is followed by six consecutive components. See Fig. 8.6.

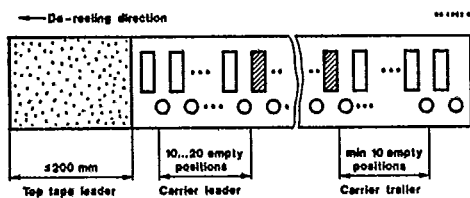


Fig. 8.6 Beginning and end of the reel

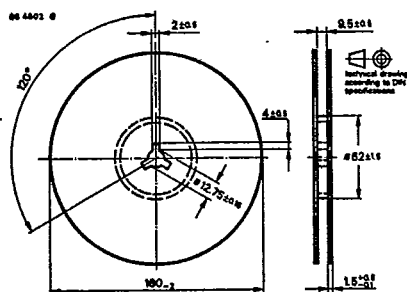


Fig. 8.7 Dimensions of the reel in mm